

# **ISC Silicon NPN Power Transistor**

2SD957

#### **DESCRIPTION**

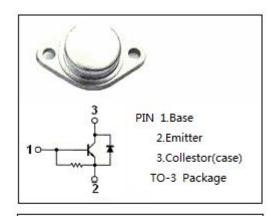
- · High Breakdown Voltage-
  - : V<sub>CBO</sub>= 1500V (Min)
- · Low Collector Saturation Voltage-
  - : V<sub>CE(sat)</sub>= 1.0V(Max.)@ I<sub>C</sub>= 4.5A
- · Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

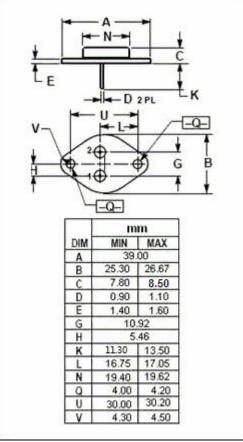


• Designed for line-operated horizontal deflection output applications.

## ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	1500	V	
Vces	Collector-Emitter Voltage	1500	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
Ic	Collector Current- Continuous 6		А	
Іср	Collector Current- Peak	10	Α	
Pc	Collector Power Dissipation @ T <sub>C</sub> = 25 °C	50	W	
Тл	Junction Temperature	150	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature Range -65~150		$^{\circ}$	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{EBO}$	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 200mA; I <sub>C</sub> = 0	5.0			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 6A; I <sub>B</sub> = 1.2A			5.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	Ic= 6A; I <sub>B</sub> = 1.2A			1.5	V
І <sub>сво</sub>	Collector Cutoff Current	V <sub>CB</sub> = 750V; I <sub>E</sub> = 0			50	μ <b>А</b>
		V <sub>CB</sub> = 1500V; I <sub>E</sub> = 0			0.5	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	8		36	
V <sub>ECF</sub>	C-E Diode Forward Voltage	I <sub>F</sub> = 6A			2.0	V
t <sub>stg</sub>	Storage Time	L = CA   = 4 2A   . = 40 v   l			10	μS
t <sub>f</sub>	Fall Time	I <sub>C</sub> = 6A, I <sub>Bend</sub> = 1.2A; L <sub>B</sub> = 10 μ H			1.5	μ \$

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